

General Description

This P-Channel enhancement mode power FETs are produced with high cell density, DMOS trench technology, which is especially used to minimize on-state resistance. This device is particularly suited for low voltage application such as portable equipment, power management and other battery powered circuits, and low inline power loss are needed in a very small outline surface mount package.

Features

- Advanced high cell density Trench technology
- Super Low Gate Charge
- Excellent CdV/dt effect decline
- 100% EAS Guaranteed
- Green Device Available

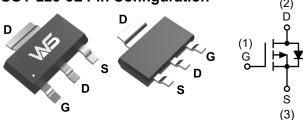
Product Summery

BV _{DSS}	R _{DSON}	I _D
-60V	175m Ω	-2A

Applications

- High Frequency Point-of-Load Synchronous Buck Converter.
- Networking DC-DC Power System
- Load Switch

SOT-223-3L Pin Configuration



Absolute Maximum Ratings

Symbol	Parameter	Rating	Units
V _{DS}	Drain-Source Voltage	-60	V
V_{GS}	Gate-Source Voltage	±20	V
I _D @T _A =25℃	Continuous Drain Current, V _{GS} @ -10V	-2	А
I _D @T _A =70℃	Continuous Drain Current, V _{GS} @ -10V	-1.6	А
I _{DM}	Pulsed Drain Current	-10	Α
P _D @T _A =25℃	Total Power Dissipation	2	W
T _{STG}	Storage Temperature Range	-55 to 150	$^{\circ}$
T_J	Operating Junction Temperature Range	-55 to 150	$^{\circ}$

Thermal Data

Symbol	Parameter	Тур.	Max.	Unit
$R_{ heta JA}$	Thermal Resistance Junction-Ambient		62	°C/W
$R_{ heta JC}$	Thermal Resistance Junction-Case		5.4	°C/W



Electrical Characteristics (T_J=25 °C, unless otherwise noted)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit	
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V , I _D =-250uA	-60			V	
$\triangle BV_{DSS}/\triangle T_{J}$	BV _{DSS} Temperature Coefficient	Reference to 25°C , I _D =-1mA		-0.03		V/°C	
D	Static Drain-Source On-Resistance	V _{GS} =-10V , I _D =-2A		175	215	mO.	
R _{DS(ON)}	Static Drain-Source On-Resistance	V _{GS} =-4.5V , I _D =-2A		205	260	mΩ	
V _{GS(th)}	Gate Threshold Voltage	V _{GS} =V _{DS} . I _D =-250uA	-1.2	-1.9	-3.0	V	
$\triangle V_{GS(th)}$	V _{GS(th)} Temperature Coefficient	V _{GS} -V _{DS} , I _D 250uA		4.56		mV/℃	
l	Drain-Source Leakage Current	V_{DS} =-60V , V_{GS} =0V , T_{J} =25 $^{\circ}\mathrm{C}$			-1		
I _{DSS}	Drain-Source Leakage Current	V_{DS} =-60V , V_{GS} =0V , T_{J} =55 $^{\circ}\mathrm{C}$			-5	uA	
I _{GSS}	Gate-Source Leakage Current	V_{GS} = $\pm 20 V$, V_{DS} = $0 V$			±100	nA	
gfs	Forward Transconductance	V _{DS} =-15V , I _D =-2A		5		S	
Qg	Total Gate Charge			6.3			
Q _{gs}	Gate-Source Charge	V _{DS} =-48V , V _{GS} =-4.5V , I _D =-1A		2.3		nC	
Q _{gd}	Gate-Drain Charge			1.8			
T _{d(on)}	Turn-On Delay Time			3			
T _r	Rise Time	V _{DD} =-30V , V _{GS} =-10V ,		20			
T _{d(off)}	Turn-Off Delay Time	R_{GEN} =3.3 Ω ,RL=30 Ω .		3.8		ns	
T _f	Fall Time			5.2			
C _{iss}	Input Capacitance			364			
Coss	Output Capacitance	V _{DS} =-15V , V _{GS} =0V , f=1MHz		41		pF	
C _{rss}	Reverse Transfer Capacitance			12			

Diode Characteristics

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
Is	Continuous Source Current	V _G =V _D =0V , Force Current			-2	Α
V_{SD}	Diode Forward Voltage	V _{GS} =0V , I _S =-1.2A , T _J =25℃			-1.2	V

A: The value of R0JA is measured with the device mounted on 1in² FR-4 board with 2oz. Copper, in a still air environment with TA =25°C. The value in any given application depends on the user's specific board design.

- B: The power dissipation PD is based on TJ(MAX)=150 °C , u s i n g ≤10s junction-to-ambient thermal resistance.
- C: Repetitive rating, pulse width limited by junction temperature TJ(MAX)=150℃. Ratings are based on low frequency and duty cycles to keep initial T J=25℃.
- D: The RθJA is the sum of the thermal impedence from junction to lead RθJA and lead to ambient.
- E: The static characteristics in Figures 1 to 6 are obtained using <300µs pulses, duty cycle 0.5% max.
- F:These curves are based on the junction-to-ambient thermal impedence which is measured with the device mounted on 1in² FR-4 board with2oz. Copper, assuming a maximum junction temperature of TJ(MAX)=150°C. The SOA curve provides a single pulse rating.



Typical Characteristics

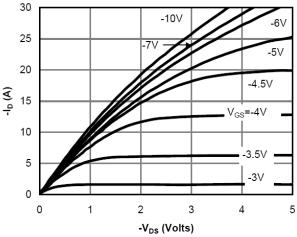


Fig 1: On-Region Characteristics

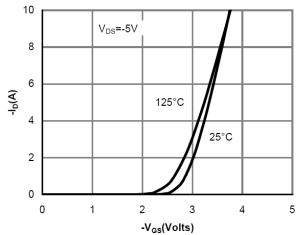


Figure 2: Transfer Characteristics

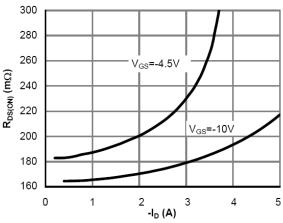


Figure 3: On-Resistance vs. Drain Current and Gate Voltage

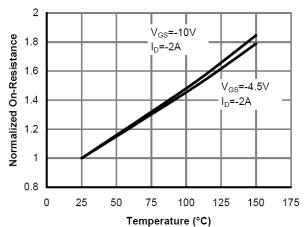


Figure 4: On-Resistance vs. Junction
Temperature

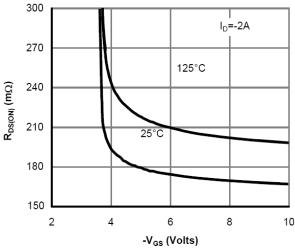


Figure 5: On-Resistance vs. Gate-Source Voltage

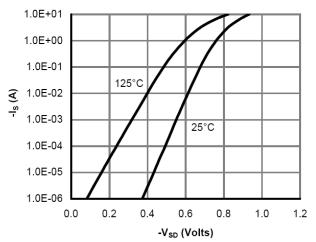


Figure 6: Body-Diode Characteristics



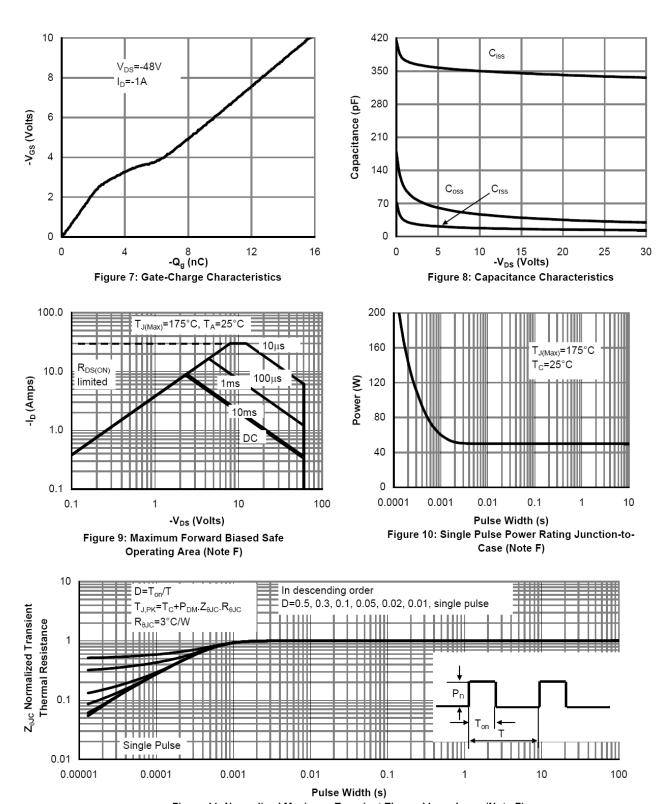
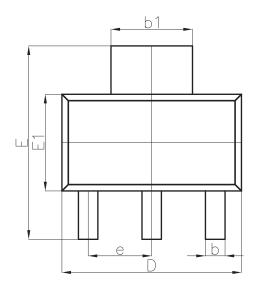
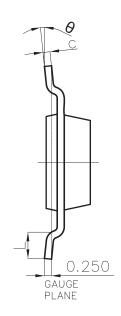


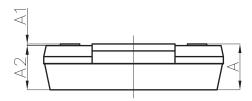
Figure 11: Normalized Maximum Transient Thermal Impedance (Note F)



Packaging information







Symbol	Dimensions In M	Dimensions In Millimeters		Inches
Symbol	Min.	Max.	Min.	Max.
A		1.800		0. 071
A1	0.020	0. 100	0.001	0.004
A2	1.500	1. 700	0. 059	0.067
b	0.660	0.840	0.026	0. 033
b1	2. 900	3. 100	0.114	0. 122
С	0. 230	0.350	0.009	0.014
D	6. 300	6. 700	0. 248	0. 264
Е	6. 700	7. 300	0. 264	0. 287
E1	3. 300	3. 700	0. 130	0. 146
е	2. 300 (BSC)		0.091 (E	SSC)
L	0.750		0.030	
θ	0°	10°	0°	10°



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